

DESCRIPTION The 2SK830 is N-channel MOS Field Effect Power Transistor designed for switching power supplies DC-DC converters.

- FEATURES**
- Suitable for switching power supplies, actuator controls, and pulse circuits
 - Low $R_{DS(on)}$
 - No second breakdown
 - Isolated mold package

ABSOLUTE MAXIMUM RATINGS

Maximum Temperatures

Storage Temperature -55 to +150 °C

Channel Temperature 150 °C Maximum

Maximum Power Dissipation ($T_c = 25\text{ °C}$)

Total Power Dissipation 95 W

Maximum Voltages and Currents ($T_a = 25\text{ °C}$)

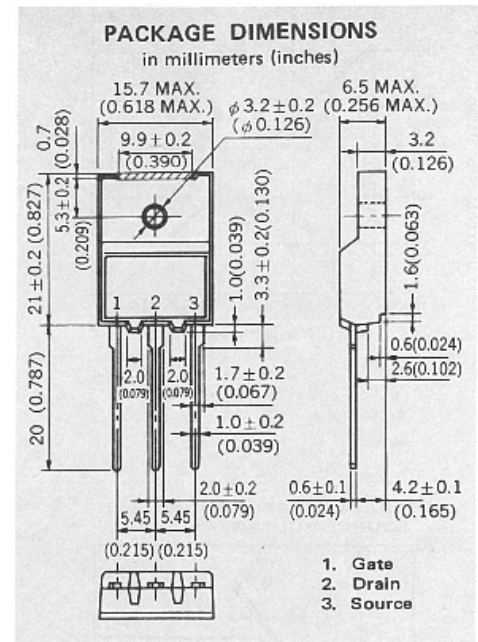
V_{DSS} Drain to Source Voltage 500 V

V_{GSS} Gate to Source Voltage ± 20 V

$I_{D(DC)}$ Drain Current (DC) ± 15 A

$I_{D(pulse)}$ Drain Current (pulse)* ± 60 A

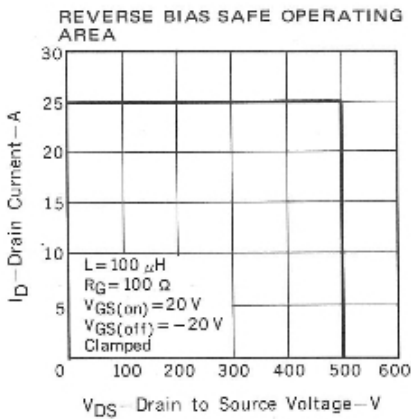
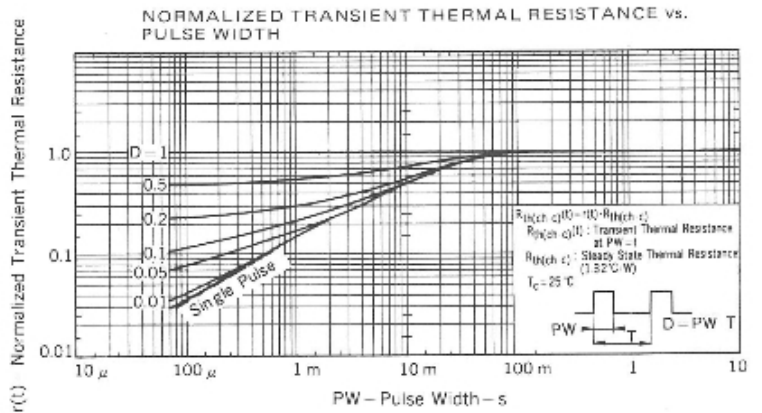
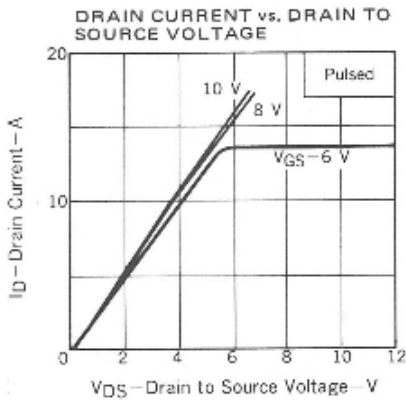
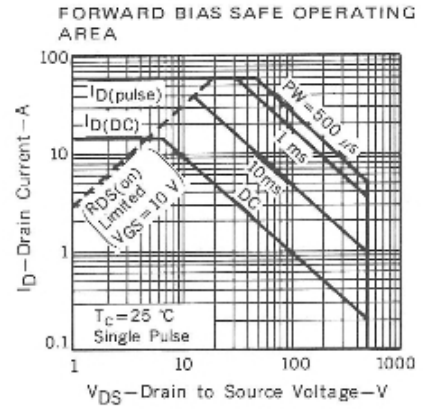
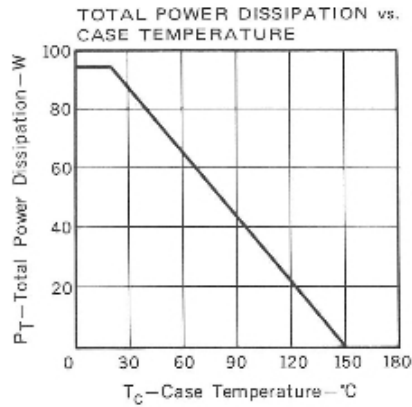
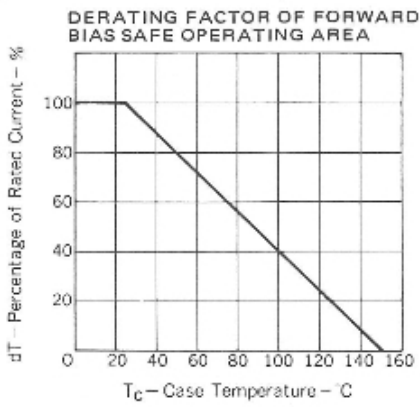
* $PW \leq 300\ \mu s$, Duty Cycle $\leq 2\%$



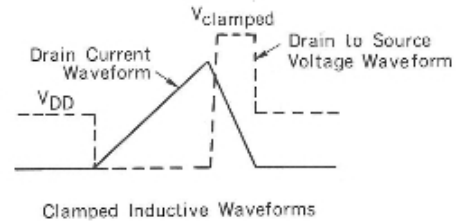
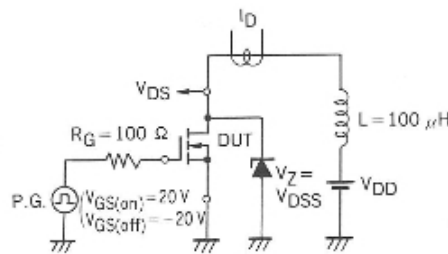
ELECTRICAL CHARACTERISTICS ($T_a = 25\text{ °C}$)

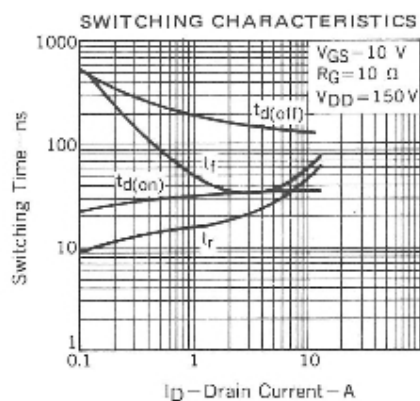
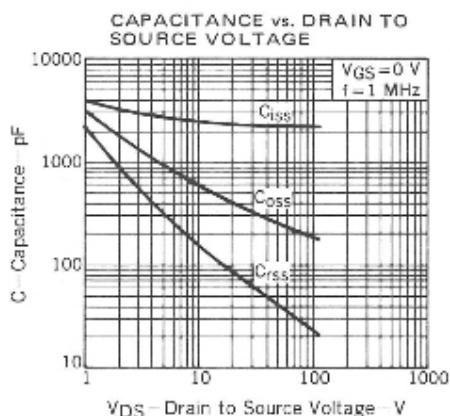
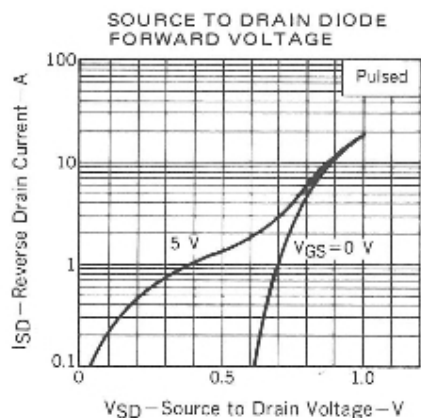
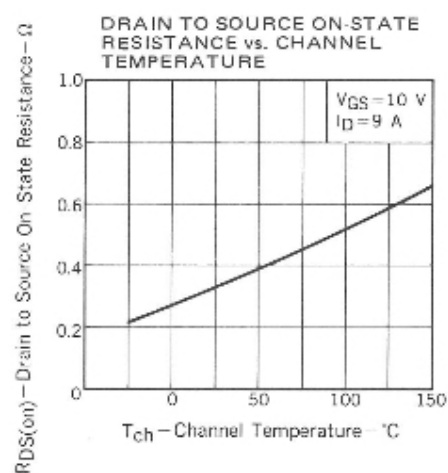
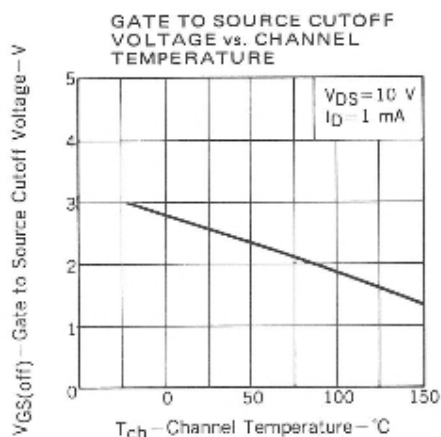
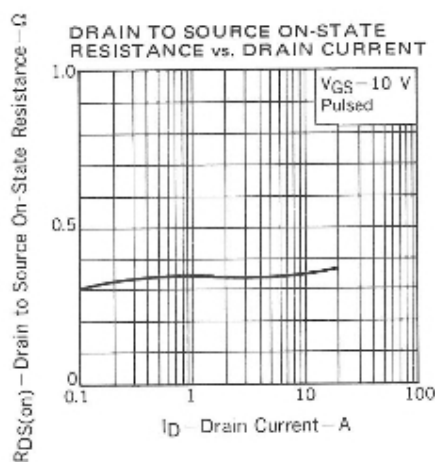
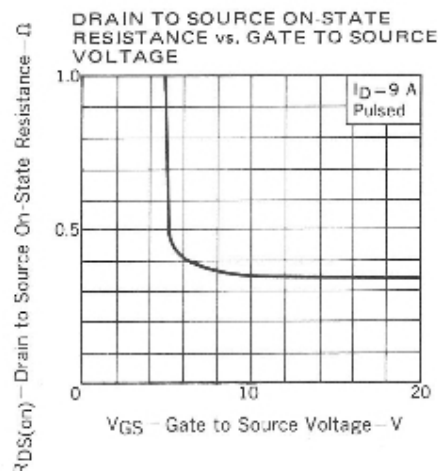
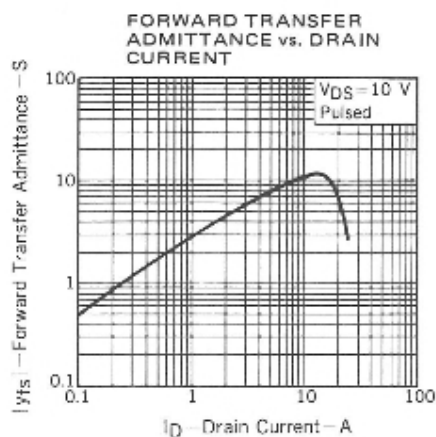
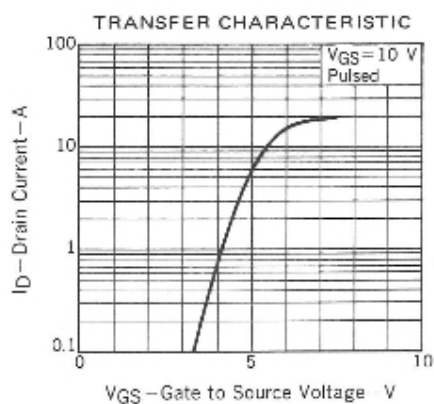
SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
I_{DSS}	Drain Leakage Current			100	μA	$V_{DS} = 500\text{ V}, V_{GS} = 0$
I_{GSS}	Gate to Source Leakage Current			± 100	nA	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0$
$V_{GS(off)}$	Gate to Source Cutoff Voltage	1.5		3.5	V	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$
$ Y_{fs} $	Forward Transfer Admittance	8.0			S	$V_{DS} = 10\text{ V}, I_D = 9\text{ A}$
$R_{DS(on)}$	Drain to Source On-State Resistance		0.35	0.45	Ω	$V_{GS} = 10\text{ V}, I_D = 9\text{ A}$
C_{iss}	Input Capacitance		2600		pF	$V_{DS} = 10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$
C_{oss}	Output Capacitance		620		pF	
C_{rss}	Reverse Transfer Capacitance		170		pF	
$t_{d(on)}$	Turn-On Delay Time		35		ns	
t_r	Rise Time		55		ns	$I_D = 9\text{ A}, V_{DD} = 150\text{ V}$ $V_{GS(on)} = 10\text{ V}$ $R_L = 16\ \Omega$ $R_{in} = 10\ \Omega$
$t_{d(off)}$	Turn-Off Delay Time		150		ns	
t_f	Fall Time		55		ns	

TYPICAL CHARACTERISTICS ($T_{\theta} = 25^{\circ}\text{C}$)



CLAMPED INDUCTIVE TEST CIRCUIT





SWITCHING TIME TEST CIRCUIT

